

Molding Type Module IGBT, 1-in-1 Package, 1200 V and 600 A



Double INT-A-PAK

FEATURES

- High short circuit capability, self limiting to $6 \times I_C$
- $10 \mu s$ short circuit capability
- $V_{CE(on)}$ with positive temperature coefficient
- Low inductance case
- Fast and soft reverse recovery antiparallel FWD
- Isolated copper baseplate using DCB (Direct Copper Bonding) technology
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- AC inverter drives
- Switching mode power supplies
- Electronic welder at f_{sw} up to 20 kHz

DESCRIPTION

Vishay's IGBT power module provides ultralow conduction loss as well as short circuit ruggedness. It is designed for applications such as inverters and UPS.

PRODUCT SUMMARY	
V_{CES}	1200 V
I_C at $T_C = 80^\circ\text{C}$	600 A
$V_{CE(on)}$ (typical) at $I_C = 600 \text{ A}, 25^\circ\text{C}$	1.9 V
Speed	8 kHz to 30 kHz
Package	Double INT-A-PAK
Circuit	Single switch with AP diode

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Collector to emitter voltage	V_{CES}		1200	V
Gate to emitter voltage	V_{GES}		± 20	
Collector current at $T_J = 150^\circ\text{C}$	I_C	$T_C = 25^\circ\text{C}$	910	A
		$T_C = 80^\circ\text{C}$	600	
Pulsed collector current	$I_{CM}^{(1)}$	$T_C = 80^\circ\text{C}$	1200	
Diode continuous forward current	I_F	600		
Diode maximum forward current	I_{FM}		1200	
Maximum power dissipation	P_D		3125	
Short circuit withstand time	t_{SC}	$T_J = 125^\circ\text{C}$	10	μs
RMS isolation voltage	V_{ISOL}	$f = 50 \text{ Hz}, t = 1 \text{ min}$	2500	V
I^2t -value, diode	I^2t	$V_R = 0 \text{ V}, t = 10 \text{ ms}, T_J = 125^\circ\text{C}$	74 000	A^2s

Note

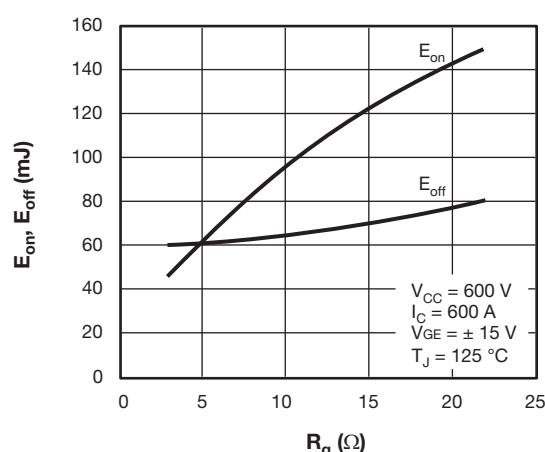
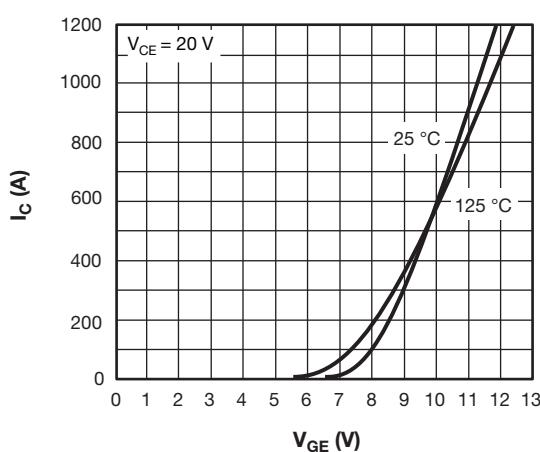
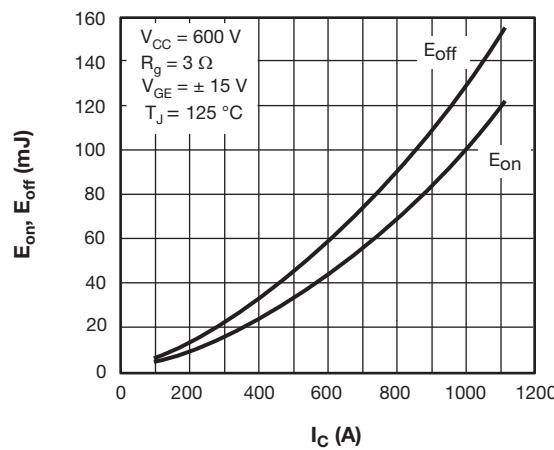
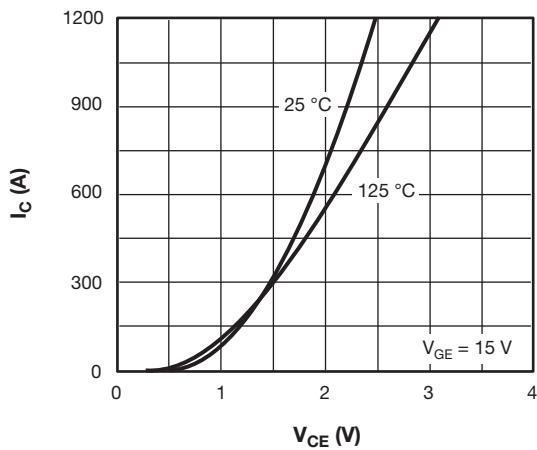
(1) Repetitive rating: pulse width limited by maximum junction temperature.

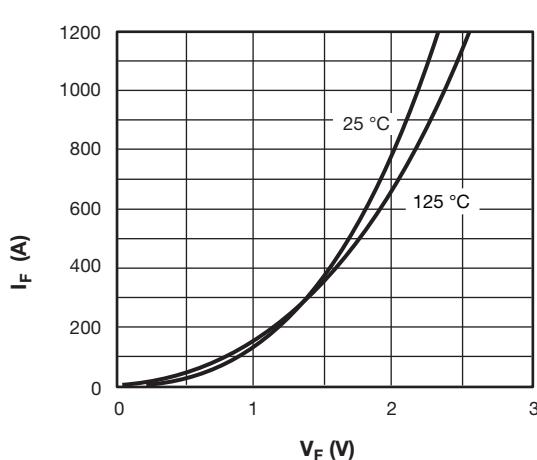
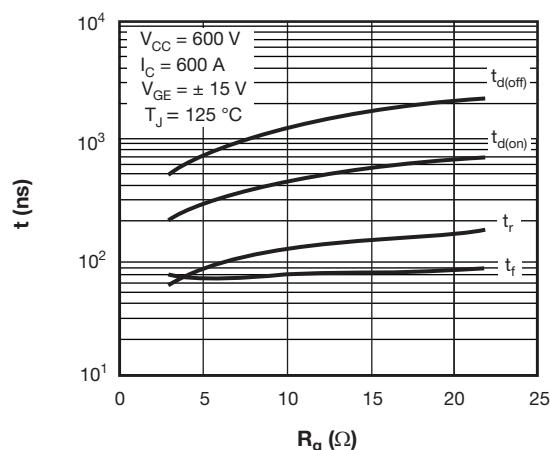
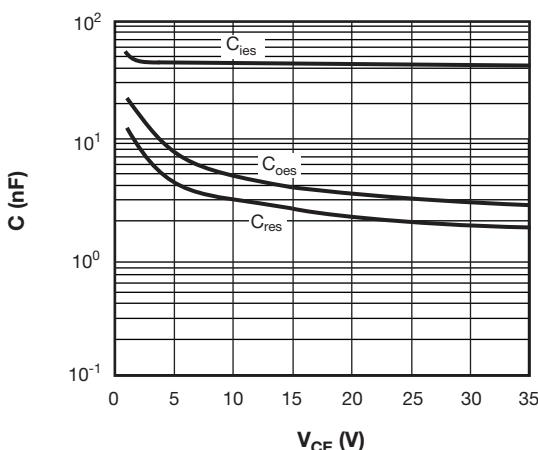
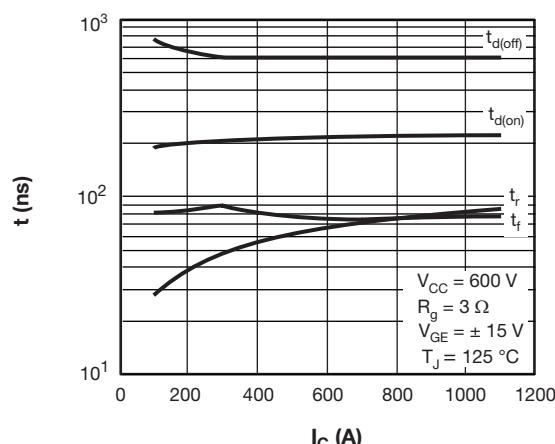
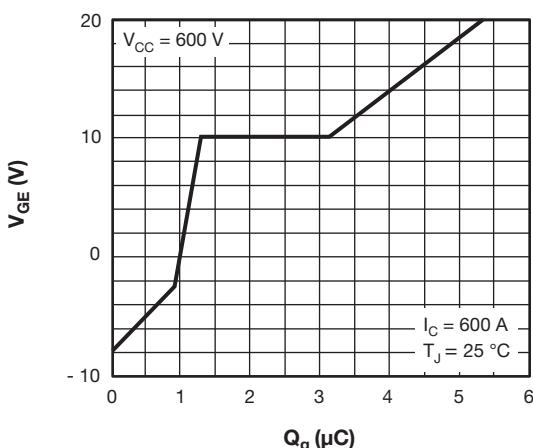
IGBT ELECTRICAL SPECIFICATIONS ($T_C = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CES}}$	$T_J = 25^\circ\text{C}$	1200	-	-	V
Collector to emitter voltage	$V_{\text{CE}(\text{on})}$	$V_{\text{GE}} = 15\text{ V}, I_C = 600\text{ A}, T_J = 25^\circ\text{C}$	-	1.9	-	
		$V_{\text{GE}} = 15\text{ V}, I_C = 600\text{ A}, T_J = 125^\circ\text{C}$	-	2.1	-	
Gate to emitter threshold voltage	$V_{\text{GE}(\text{th})}$	$V_{\text{CE}} = V_{\text{GE}}, I_C = 24\text{ mA}, T_J = 25^\circ\text{C}$	5.0	6.2	7.0	
Collector cut-off current	I_{CES}	$V_{\text{CE}} = V_{\text{CES}}, V_{\text{GE}} = 0\text{ V}, T_J = 25^\circ\text{C}$	-	-	5.0	mA
Gate to emitter leakage current	I_{GES}	$V_{\text{GE}} = V_{\text{GES}}, V_{\text{CE}} = 0\text{ V}, T_J = 25^\circ\text{C}$	-	-	400	nA

SWITCHING CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{CC}} = 600\text{ V}, I_C = 600\text{ A}, R_g = 3\Omega, V_{\text{GE}} = \pm 15\text{ V}, T_J = 25^\circ\text{C}$	-	200	-	ns
Rise time	t_r		-	62	-	
Turn-off delay time	$t_{\text{d}(\text{off})}$		-	510	-	
Fall time	t_f		-	60	-	
Turn-on switching loss	E_{on}	$V_{\text{CC}} = 600\text{ V}, I_C = 600\text{ A}, R_g = 3\Omega, V_{\text{GE}} = \pm 15\text{ V}, T_J = 25^\circ\text{C}$	-	39	-	mJ
Turn-off switching loss	E_{off}		-	48	-	
Turn-on delay time	$t_{\text{d}(\text{on})}$		-	210	-	
Rise time	t_r		-	65	-	
Turn-off delay time	$t_{\text{d}(\text{off})}$	$V_{\text{CC}} = 600\text{ V}, I_C = 600\text{ A}, R_g = 3\Omega, V_{\text{GE}} = \pm 15\text{ V}, T_J = 125^\circ\text{C}$	-	600	-	ns
Fall time	t_f		-	75	-	
Turn-on switching loss	E_{on}		-	45	-	
Turn-off switching loss	E_{off}		-	60	-	
Input capacitance	C_{ies}	$V_{\text{GE}} = 0\text{ V}, V_{\text{CE}} = 25\text{ V}, f = 1.0\text{ MHz}$	-	41.0	-	nF
Output capacitance	C_{oes}		-	3.1	-	
Reverse transfer capacitance	C_{res}		-	2.0	-	
SC data	I_{SC}	$t_{\text{SC}} \leq 10\text{ }\mu\text{s}, V_{\text{GE}} = 15\text{ V}, T_J = 25^\circ\text{C}, V_{\text{CC}} = 900\text{ V}, V_{\text{CEM}} \leq 1200\text{ V}$	-	2600	-	A
Stray inductance	L_{CE}		-	-	20	nH
Module lead resistance, terminal to chip	$R_{\text{CC}+\text{EE}}$	$T_C = 25^\circ\text{C}$	-	0.18	-	m Ω

DIODE ELECTRICAL SPECIFICATIONS ($T_C = 25^\circ\text{C}$ unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Diode forward voltage	V_F	$I_F = 600\text{ A}$	$T_J = 25^\circ\text{C}$	-	1.8	2.4	V
			$T_J = 125^\circ\text{C}$	-	1.9	-	
Diode reverse recovery charge	Q_{rr}	$I_F = 600\text{ A}, V_R = 600\text{ V}, dI_F/dt = -6000\text{ A}/\mu\text{s}, V_{\text{GE}} = -15\text{ V}$	$T_J = 25^\circ\text{C}$	-	65	-	μC
			$T_J = 125^\circ\text{C}$	-	100	-	
Diode peak reverse recovery current	I_{rr}	$I_F = 600\text{ A}, V_R = 600\text{ V}, dI_F/dt = -6000\text{ A}/\mu\text{s}, V_{\text{GE}} = -15\text{ V}$	$T_J = 25^\circ\text{C}$	-	450	-	A
			$T_J = 125^\circ\text{C}$	-	510	-	
Diode reverse recovery energy	E_{rec}		$T_J = 25^\circ\text{C}$	-	35	-	μJ
			$T_J = 125^\circ\text{C}$	-	42	-	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Operating temperature range	T_J			-40	-	150	°C
Storage temperature range	T_{Stg}			-40	-	125	°C
Junction to case per module	IGBT	R_{thJC}		-	-	0.04	K/W
	Diode			-	-	0.09	
Case to sink	R_{thCS}	Conductive grease applied		-	0.035	-	
Mounting torque			Power terminal screw: M6	2.5 to 5.0			Nm
			Mounting screw: M6	3.0 to 6.0			
Weight				310		g	





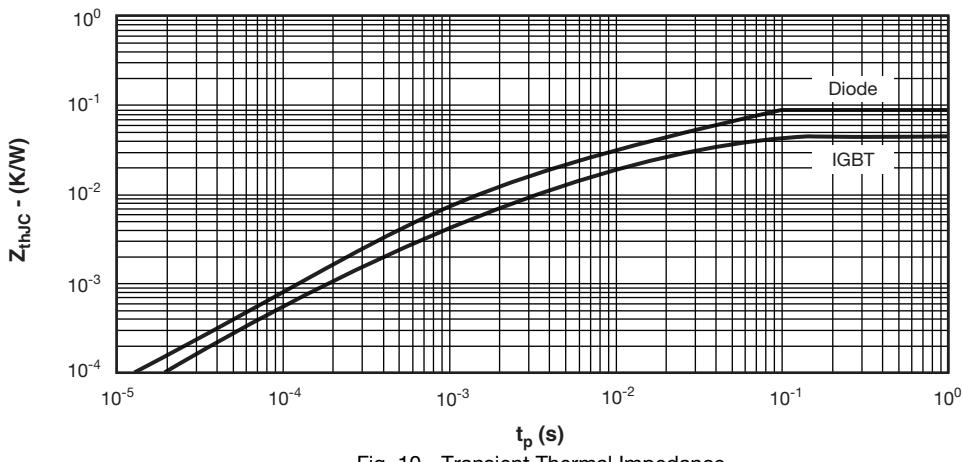
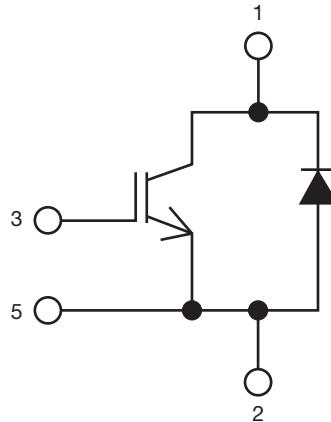


Fig. 10 - Transient Thermal Impedance

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95526

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